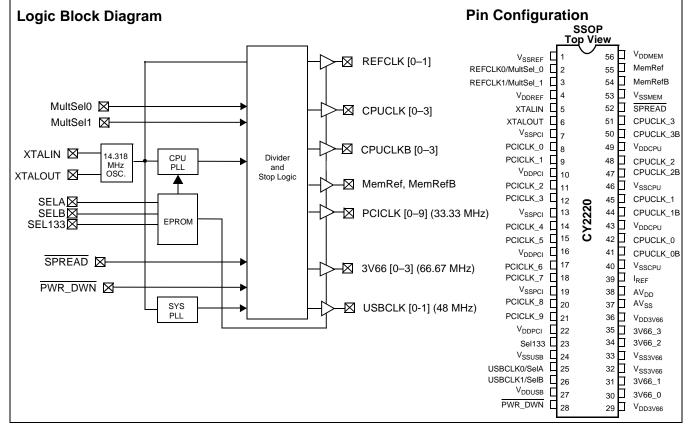


133-MHz Spread Spectrum Clock Synthesizer/Driver with Differential CPU Outputs

Features	Benefits
Compliant to Intel® CK00 Clock Synthesizer/Driver Specifications	Supports next generation Pentium® processors using differential clock drivers
Multiple output clocks at different frequencies	Motherboard clock generator
— Four pairs of differential CPU outputs, up to 133 MHz	 Support Multiple CPUs and a chipset
—Ten synchronous PCI clocks	 Support for PCI slots and chipset
Two Memory Reference clocks, 180 degrees out of phase	— Drives up to two Direct Rambus™ Clock Generators (DRCG)
— Four AGP and Hub Link clocks at 66 MHz	 Supports USB host controller and SuperI/O chip
— Two 48-MHz clocks	— Supports ISA slots and I/O chip
— Two reference clocks at 14.318 MHz	
Spread Spectrum clocking	Enables reduction of EMI and overall system cost
—31 kHz modulation frequency	
— Default is -0.6%, which is recommended by Intel	
Power-down features	Enables ACPI compliant designs
Three Select inputs	Supports up to eight CPU clock frequencies
Low-skew and low-jitter outputs	Meets tight system timing requirements at high frequency
OE and Test Mode support	Enables ATE and "bed of nails" testing
56-pin SSOP package	Widely available, standard package enables lower cost



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Pin Summary

Name	Pins	Description			
V _{SSREF}	1	3.3V Reference ground			
V _{DDREF}	4	3.3V Reference voltage supply			
V _{SSPCI}	7, 13, 19	3.3V PCI ground			
V _{DDPCI}	10, 16, 22	3.3V PCI voltage supply			
V _{SS3V66}	32, 33	3.3V AGP and Hub Link ground			
V _{DD3V66}	29, 36	3.3V AGP and Hub Link voltage supply			
V _{SSUSB}	24	3.3V USB ground			
V _{DDUSB}	27	3.3V USB voltage supply			
V _{SSCPU}	40, 46	3.3V CPU ground			
V _{DDCPU}	43, 49	3.3V CPU voltage supply			
V _{SSMEM}	53	3.3V Memory ground			
V _{DDMEM}	56	3.3V Memory voltage supply			
AV _{SS}	37	Analog ground for PLL and Core			
AV _{DD}	38	Analog voltage supply to PLL and Core			
I _{REF}	39	Reference current for external biasing			
XTALIN ^[1]	5	Reference crystal input			
XTALOUT ^[1]	6	Reference crystal feedback			
CPUCLK [0-3]	42, 45, 48, 51	CPU clock outputs			
CPUCLK [0-3]B	41, 44, 47, 50	Inverse CPU clock outputs			
PCICLK [0-9]	8, 9, 11, 12, 14, 15, 17, 18, 20, 21	PCI clock outputs, synchronously running at 33.33 MHz			
MemRef	55	MemRef clock output, drives memory clock generator			
MemRefB	54	MemRefB clock output 180 degrees out of phase with MemRef			
3V66_[0-3]	30, 31, 34, 35	AGP and Hub Link clock outputs, running at 66 MHz			
USBCLK [0-1]/Sel[A-B]	25, 26	Sel [A–B] inputs are sensed then internally latched on power-up before the pins are used for 48-MHz USB clock outputs			
REFCLK[0-1]/MultSel[0-1]	2, 3	MultSel[0–1] inputs are sensed then internally latched on power-up before the pins are Reference clock outputs, 14.318 MHz			
PWR_DWN	28	Active LOW input, powers down part when asserted			
SPREAD ^[2]	52	Active LOW input, enables spread spectrum when asserted			
SEL133	23	CPU frequency select input (See Function Table)			

Notes:

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^{1.} For best accuracy, use a parallel-resonant crystal, C_{LOAD} = 18 pF. For crystals with different C_{LOAD} , please refer to the application note, "Crystal Oscillator Topics."

2. Input is static HIGH or LOW. Frequency of toggling cannot exceed 30 MHz.



Function Table^[3]

SEL133	SELA	SELB	CPUCLK (MHz)	MemRef (MHz)	3V66CLK (MHz)	PCICLK (MHz)	USBCLK (MHz)	REFCLK (MHz)
0	0	0	100	50	66	33	48	14.318
0	0	1	N/A	N/A	N/A	N/A	N/A	N/A
0	1	0	N/A	N/A	N/A	N/A	N/A	N/A
0	1	1	Hi-Z	Hi-Z	Hi-Z	Hi-Z	Hi-Z	Hi-Z
1	0	0	133	66	66	33	48	14.318
1	0	1	N/A	N/A	N/A	N/A	N/A	N/A
1	1	0	N/A	N/A	N/A	N/A	N/A	N/A
1	1	1	TCLK/2	TCLK/4	TCLK/4	TCLK/8	TCLK/2	TCLK

Actual Clock Frequency Values

	Target	CY2220-	·1	CY2220-2		
Clock Output	Frequency (MHz)	Actual Frequency (MHz)	PPM	Actual Frequency (MHz)	PPM	
CPUCLK	100	99.126	-8741	100.227	+2270	
CPUCLK	133	132.769	-1740	133.269	+2022	
USBCLK	48	48.008	167	48.008	167	

Swing Select Functions

MultSel0	MultSel1 Board Target		Reference R, I _{REF} =	Output Current	V _{OH} @ Z, Iref = 2.32 mA
0	0	60Ω	Rr = 475 ± 1%, Iref = 2.32 mA	I _{OH} = 5*Iref	0.71 @ 60
0	0	50Ω	Rr = 475 ± 1%, Iref = 2.32 mA	I _{OH} = 5*Iref	0.59 @ 50
0	1	1 60Ω Rr = 475 ± 1%, Iref = 2.32 mA		I _{OH} = 6*Iref	0.85 @ 60
0	1	50Ω	Rr = 475 ± 1%, Iref = 2.32 mA	I _{OH} = 6*Iref	0.71 @ 50
1	0	60Ω	Rr = 475 ± 1%, Iref = 2.32 mA	I _{OH} = 4*Iref	0.56 @ 60
1	0	50Ω	Rr = 475 ± 1%, Iref = 2.32 mA	I _{OH} = 4*Iref	0.47 @ 50
1	1	60Ω	Rr = 475 ± 1%, Iref = 2.32 mA	I _{OH} = 7*Iref	0.99 @ 60
1	1	50Ω	Rr = 475 ± 1%, Iref = 2.32 mA	I _{OH} = 7*Iref	0.82 @ 50

Clock Driver Impedances

				Impedance	
Buffer Name	V _{DD} Range	Buffer Type	$\begin{array}{c} \textbf{Minimum} \\ \Omega \end{array}$	Typical Ω	$\begin{array}{c} \mathbf{Maximum} \\ \Omega \end{array}$
CPUCLK, CPUCLKB		Type X1			
USB, REF	3.135-3.465	Type 3	20	40	60
PCI, 3V66	3.135–3.465	Type 5	12	30	55
MemRef, MemRefB	3.135-3.465	Type 5	12	30	55

Note:

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^{3.} TCLK is a test clock driven in on the XTALIN input in test mode.



Maximum Ratings

(Above which the useful life may be impaired. For user guidelines, not tested.)

Supply Voltage.....-0.5 to +7.0V Input Voltage....-0.5V to $V_{\rm DD}$ + 0.5

Storage Temperature (Non-Condensing)65°C to +150°C
Junction Temperature+150°C
Package Power Dissipation1W
Static Discharge Voltage (per JEDEC EIA/JESD22-A114-A)2000V

Operating Conditions Over which Electrical Parameters are Guaranteed

Parameter	Description	Min.	Max.	Unit
V _{DDREF} , V _{DDPCI} , AV _{DD} , V _{DD3V66} , V _{DDUSB} , V _{DDCPU} , V _{DDMEM}	3.3V Supply Voltages	3.135	3.465	V
T _A	Operating Temperature, Ambient	0	70	°C
C _{in}	Input Pin Capacitance Nominal Value	18 pF	18 pF	pF
C _{XTAL}	XTAL Pin Capacitance		22.5	pF
C _L	Max. Capacitive Load on MemRef, USBCLK, REF PCICLK, 3V66		20 30	pF
f _(REF)	Reference Frequency, Oscillator Nominal Value	14.318	14.318	MHz
t _{PU}	Power-up time for all VDD's to reach minimum specified voltage (power ramps must be monotonic)	0.05	50	ms

Electrical Characteristics Over the Operating Range

Parameter	Description	Test Conditions			Max.	Unit
V _{IH}	High-level Input Voltage	Except Crystal Pads. Threshold voltage	for crystal pads = V _{DD} /2	2.0		V
V _{IL}	Low-level Input Voltage	Except Crystal Pads			0.8	V
V _{OH}	High-level Output Voltage	MemRef, USB, REF, 3V66	MemRef, USB, REF, 3V66 $I_{OH} = -1 \text{ mA}$			V
		PCI	I _{OH} = -1 mA	2.4		V
V _{OL}	Low-level Output Voltage	MemRef, USB, REF, 3V66	I _{OL} = 1 mA		0.4	V
		PCI	I _{OL} = 1 mA		0.55	V
I _{IH}	Input High Current	$0 \le V_{IN} \le V_{DD}$	-5	5	μΑ	
I _{IL}	Input Low Current	$0 \le V_{IN} \le V_{DD}$			5	μΑ
I _{OH}	High-level Output Current	CPU For I _{OH} =6*IRef Configuration	Type X1, V _{OH} = 0.65V	-12.9	-14.9	mA
		USB, REF	Type 3, V _{OH} = 2.4V	-15	- 51	1
		3V66, PCI, MemRef, MemRefB	Type 5, V _{OH} = 2.4V	-30	-100	
I _{OL}	Low-level Output Current	USB, REF	Type 3, $V_{OL} = 0.4V$	10	24	mA
		3V66, PCI, MemRef, MemRefB	Type 5, V _{OL} =0.4 V	20	49	
I _{OZ}	Output Leakage Current	Three-state			10	μА
I _{DD3}	3.3V Power Supply Current	AV _{DD} /V _{DD33} = 3.465V, F _{CPU} = 133 MHz			250	mΑ
I _{DDPD3}	3.3V Shutdown Current	$AV_{DD}/V_{DDQ3} = 3.465V$			60	mA

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Switching Characteristics^[4] Over the Operating Range

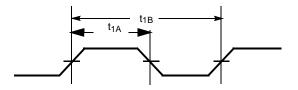
Parameter	Output	Description	Test Conditions	Min.	Max.	Unit
t ₁	All	Output Duty Cycle ^[5]	t _{1A} /(t _{1B})	45	55	%
t ₂	CPU	Rise Time	Measured at 20% to 80% of V _{OH}	175	700	ps
t ₂	USB, REF	Rising Edge Rate	Between 0.4V and 2.4V	0.5	2.0	V/ns
t ₂	PCI, 3V66, MemRef	Rising Edge Rate	Between 0.4V and 2.4V	1.0	4.0	V/ns
t ₃	CPU	Fall Time	Fall Time Measured at 80% to 20% of V _{OH}		700	ps
t ₃	USB, REF	Falling Edge Rate	Falling Edge Rate Between 2.4V and 0.4V		2.0	V/ns
t ₃	PCI, 3V66, MemRef	Falling Edge Rate	Between 2.4V and 0.4V	1.0	4.0	V/ns
t ₄	CPU	CPU-CPU Skew Measured at Crossover			150	ps
t ₅	3V66	3V66-3V66 Skew	Measured at 1.5V		250	ps
t ₆	PCI	PCI-PCI Skew	Measured at 1.5V		500	ps
t ₇	3V66,PCI	3V66-PCI Clock Skew	3V66 leads. Measured at 1.5V	1.5	3.5	ns
t ₈	CPU	Cycle-Cycle Clock Jitter	Measured at Crossover t ₈ = t _{8A} - t _{8B} With all outputs running		200	ps
t ₉	Mref	Cycle-Cycle Clock Jitter	Measured at 1.5V $t_9 = t_{9A} - t_{9B}$		250	ps
t ₉	3V66	Cycle-Cycle Clock Jitter	Measured at 1.5V $t_9 = t_{9A} - t_{9B}$		300	ps
t ₉	USB	Cycle-Cycle Clock Jitter	Measured at 1.5V $t_9 = t_{9A} - t_{9B}$		350	ps
t ₉	PCI	Cycle-Cycle Clock Jitter	Measured at 1.5V $t_9 = t_{9A} - t_{9B}$		500	ps
t ₉	REF	Cycle-Cycle Clock Jitter	Measured at 1.5V $t_9 = t_{9A} - t_{9B}$		1000	ps
	CPU, PCI	Settle Time	CPU and PCI clock stabilization from power-up		3	ms
	CPU	Rise/Fall Matching	Measured with test loads ^[6, 7]		20%	
	CPU	Overshoot	Measured with test loads ^[7]		V _{OH} + 0.2	V
	CPU	Undershoot	Measured with test loads ^[7]	-0.2		V
V _{oh}	CPU	High-level Output Voltage	Measured with test loads ^[7]	0.65	0.74	V
V _{ol}	CPU	Low-level Output Voltage	Measured with test loads ^[7]	0.0	0.05	V
V _{crossover}	CPU	Crossover Voltage	Measured with test loads ^[7]	45% of V _{OH}	55% of V _{OH}	V

- All parameters specified with loaded outputs. Parameters not tested in production, but are guaranteed by design characterization. Duty cycle is measured at 1.5V with V_{DD} at 3.3V on all output except CPU. Duty Cycle on CPU is measured at V_{Crossover}.
 Determined as a fraction of 2*(t_{RP} t_{RN})/(t_{RP} + t_{RN}) Where t_{RP} is a rising edge and t_{RN} is an intersecting falling edge.
 The test load is specified in test circuit.

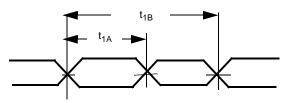


Switching Waveforms

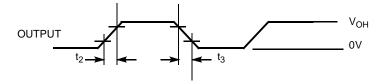
Duty Cycle Timing (Single Ended Output)



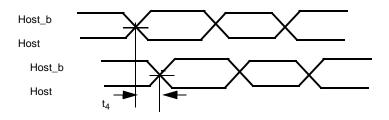
Duty Cycle Timing (CPU Differential Output)



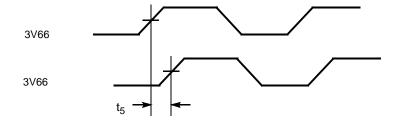
All Outputs Rise/Fall Time



CPU-CPU Clock Skew



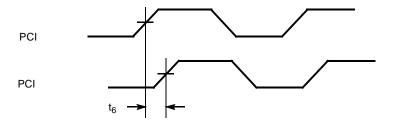
3V66-3V66 Clock Skew



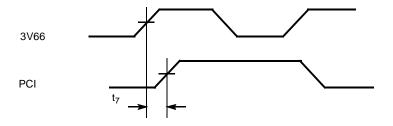


Switching Waveforms (continued)

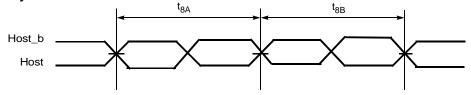
PCI-PCI Clock Skew



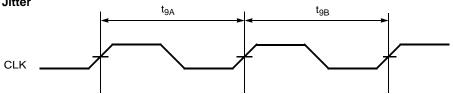
3V66-PCI Clock Skew

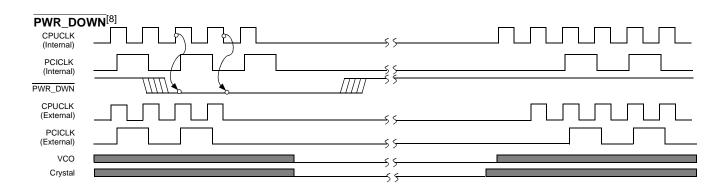


CPU Clock Cycle-Cycle Jitter



Cycle-Cycle Clock Jitter



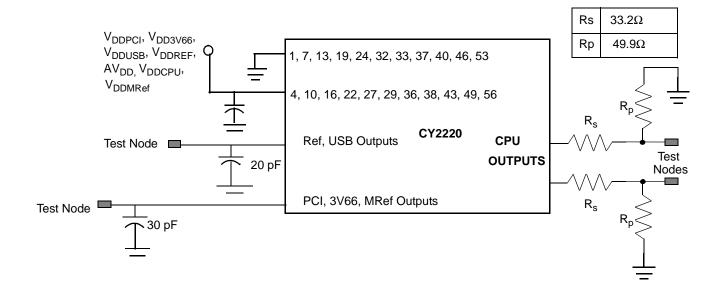


Note

^{8.} Shaded section on the VCO and Crystal waveforms indicates that the VCO and crystal oscillator are active, and there is a valid clock.



Test Circuit^[9, 10]



Ordering Information

Ordering Code	Package Name	Package Type	Operating Range
CY2220PVC-1	O56	56-Pin SSOP	Commercial
CY2220PVC-2	O56	56-Pin SSOP	Commercial

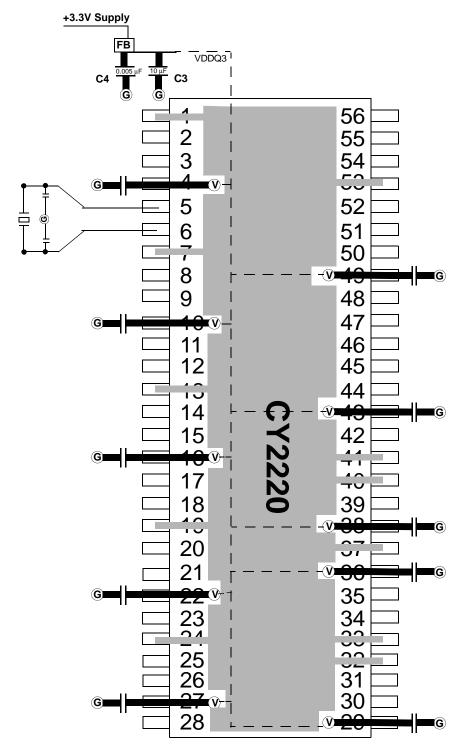
Notes:

^{9.} Each supply pin must have an individual decoupling capacitor.

^{10.} All capacitors must be placed as close to the pins as is physically possible.



Layout Example



FB = Dale ILB1206 - 300 (30 Ω @ 100 MHz)

Cermaic Caps C3 = $10-22 \mu F$ C4 = $0.005 \mu F$

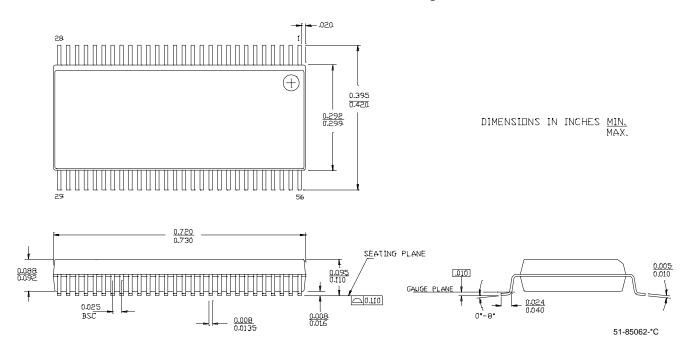
G = VIA to GND plane layer V =VIA to respective supply plane layer

Note: Each supply plane or strip should have a ferrite bead and capacitors All bypass caps = 0.01 μF ceramic



Package Diagram

56-Lead Shrunk Small Outline Package O56





Document Title: CY2220 133-MHz Spread Spectrum Clock Synthesizer/Driver with Differential CPU Outputs Document Number: 38-07206						
REV. ECN NO. Issue Orig. of Change			Description of Change			
**	111730	01/17/02	DSG	Change from Spec number: 38-00813 to 38-07206		
*A	121841	12/30/02	RBI	Power up requirements added to Operating Conditions Information		